

論文 / 著書情報  
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種別(和文)	論文要旨
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# 論文要旨

## THESIS SUMMARY

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Department of, Graduate major in	ライフエンジニアリング	コース	Academic Degree Requested	Doctor of	
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Student's Name			Chief Examiner		

### 要旨 (英文 800 語程度)

Thesis Summary (approx.800 English Words )

In this thesis, my research focuses on the molecular design of the bent-shaped dimeric molecules to adapt low temperature ferroelectric phase with high spontaneous polarization ( $P_s$ ) and dielectric strength ( $\Delta\epsilon$ ).

In Chapter 1, the background of this research was reviewed, and the significance and objective were described.

In Chapter 2, in order to grasp the  $\Delta\epsilon$  of the ferroelectric phase in the bent-shaped dimeric molecules and obtain the molecular design for the  $\Delta\epsilon$  enhancement, the dielectric relaxation properties of the ferroelectric smectic-A (SmAP<sub>F</sub>) phase formed by mixtures of bent-shaped dimeric molecules with different alkyl chain lengths was analyzed. The SmAP<sub>F</sub> phase exhibited a collective mode with cooperative dipole orientation at about 500 Hz. The  $\Delta\epsilon$  increases dramatically with increasing the liquid crystal (LC) cell thickness. It exceeds 7000 for a 50  $\mu\text{m}$ -thick cell. As the cell thickness increases, the LC domain size increases. This means that the number of interacting dipole moments is important for the achievement of the huge  $\Delta\epsilon$ .

In Chapter 3, in order to obtain the molecular design for the  $\Delta\epsilon$  enhancement, the relationship between the dielectric relaxation properties and electrical switching behaviors in the SmAP<sub>F</sub>, antiferroelectric smectic-A (SmAP<sub>A</sub>) and antiferroelectric smectic-C (SmCAP<sub>A</sub>) phases was analyzed. In the SmAP<sub>F</sub> phase, a small threshold electric field ( $E_{th}$ ) of less than 1  $\text{V}\mu\text{m}^{-1}$  for ferroelectric switching is characteristic and the  $E_{th}$  decreases with increasing cell thickness. In dielectric measurements, the SmAP<sub>F</sub> phase has a large  $\Delta\epsilon$  over 1500 in a 3  $\mu\text{m}$ -thick cell. The  $\Delta\epsilon$  greatly depends on the cell thickness, and increases up to 10000 in a 80  $\mu\text{m}$ -thick cell. In the SmAP<sub>A</sub> phase, although the  $E_{th}$  is higher than in the SmAP<sub>F</sub> phase, still low at about 2  $\text{V}\mu\text{m}^{-1}$  for a 3  $\mu\text{m}$ -thick cell. A similar cell thickness dependence is also observed, with the  $E_{th}$  decreasing to 0.6  $\text{V}\mu\text{m}^{-1}$  for an 80  $\mu\text{m}$ -thick cell. In the dielectric measurements, the SmAP<sub>A</sub> phase is a cell thickness dependence similar to the SmAP<sub>F</sub> phase, with the  $\Delta\epsilon$  increasing to 200 for the 3  $\mu\text{m}$ -thick cell and 2000 for the 80  $\mu\text{m}$ -thick cell. Another antiferroelectric phase, the SmCAP<sub>A</sub> phase, has the  $E_{th}$  of 10  $\text{V}\mu\text{m}^{-1}$  in a 3  $\mu\text{m}$ -thick cell and a very low  $\Delta\epsilon$  of 8. A plot of the obtained  $\Delta\epsilon$  versus the reciprocal  $E_{th}$  revealed that all the data were on a straight line. The lower  $E_{th}$  (i.e., the energy barrier between the two polar states) enhances the cooperative orientation of the dipoles, resulting in higher  $\Delta\epsilon$ .

In Chapter 4, in order to obtain the molecular design for the  $P_s$  enhancement, three types of the bent-shaped dimeric molecules are synthesized by fluorine substitution on the mesogenic unit and, the effect of fluorine substitution on the polar smectic phase was analyzed. The fluorine-substituted dimeric molecules form the SmAP<sub>F</sub> and SmCAP<sub>A</sub> phases, respectively, depending on the fluorine-substituted position. The fluorine substitution can increase the dipole moment of the molecule. The estimated dipole moments of the one-sided mesogens in the non-fluorinated dimeric molecule (C16), the two fluorinated dimeric molecule (2F-Y-C16) and the four fluorinated dimeric molecule (4F-XY-C16) are 5.99, 6.85 and 7.94 D, respectively. Furthermore, the reversal  $P_s$  of C16, 2F-Y-C16 and 4F-XY-C16 were 0.64, 1.64 and 2.42  $\mu\text{Ccm}^{-2}$ , respectively. A clear proportional relationship was observed by plotting the obtained  $P_s$  against the dipole moment of the one-sided mesogen. From this result, it was clarified that fluorine substitution to the mesogenic unit increases the dipole moment of the molecule, resulting in a high  $P_s$  value.

In Chapter 5, a novel dimeric molecule with large dipole moment was developed to enhance the  $P_s$  and  $\Delta\epsilon$ . A dimeric molecule, di-5(3FM-C4T), with fluorine-substituted mesogenic cores as side wings connected by a pentamethylene spacer was synthesized and demonstrated for the  $P_s$  and  $\Delta\epsilon$ . Due to effective fluorine substitution, the mesogenic core has a huge dipole moment of 11.2 D. From polarization switching, second harmonic generation and dielectric measurements, it was found to form the SmAP<sub>F</sub>, ferroelectric nematic (N<sub>F</sub>) and polar isotropic (Iso<sub>P</sub>) phases. The N<sub>F</sub> phase is composed of U-shaped molecules that behave like rod-shaped molecules. The  $P_s$  is about 8  $\mu\text{Ccm}^{-2}$ , reflecting the huge dipole moment of the mesogenic core. On the other hand, the SmAP<sub>F</sub> phase is formed by bent-shaped molecules. The N<sub>F</sub>-SmAP<sub>F</sub> phases transition has a structural change from a rod-shaped to a bent-shaped molecule, which is induced by a pentamethylene spacer in the dimeric molecule. The  $P_s$  of the SmAP<sub>F</sub> phase is about 4  $\mu\text{Ccm}^{-2}$ , which is half that of the N<sub>F</sub> phase as expected from the bent-shaped molecule, but is the highest among conventional bent-shaped LC molecules. Three polar phases were found to have a high  $\Delta\epsilon$  of 10000 reflecting the huge dipole moment and the oriented structure.

In Chapter 6, each chapter is summarized and the molecular design for high  $\Delta\epsilon$  and  $P_s$  using the bent-shaped dimeric molecules is proposed.

備考：論文要旨は、和文 2000 字と英文 300 語を 1 部ずつ提出するか、もしくは英文 800 語を 1 部提出してください。

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